

NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR
Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Part Number	R1 (NOM)	R2 (NOM)
DDC124EU	22K Ω	22K Ω
DDC144EU	47K Ω	47K Ω
DDC114YU	10K Ω	47K Ω
DDC123JU	2.2K Ω	47K Ω
DDC114EU	10K Ω	10K Ω

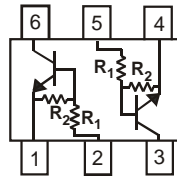
Mechanical Data

- Case: SOT363
- Case material: Molded Plastic. "Green" Molding Compound.
- Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.006 grams (approximate)

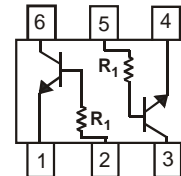
Part Number	R1 Only
DDC113TU	1K Ω
DDC143TU	4.7K Ω
DDC114TU	10K Ω



Top View



R1, R2



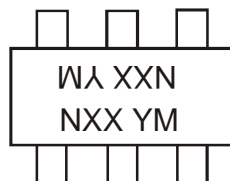
R1 Only

Device Schematic

Ordering Information (Note 3 & 4)

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDC124EU-7-F	Commercial	N17	7	8	3,000
DDC124EUQ-7-F	Automotive	N17	7	8	3,000
DDC124EUQ-13-F	Automotive	N17	13	8	10,000
DDC144EU-7-F	Commercial	N20	7	8	3,000
DDC114YU-7-F	Commercial	N14	7	8	3,000
DDC114YUQ-7-F	Automotive	N14	7	8	3,000
DDC123JU-7-F	Commercial	N06	7	8	3,000
DDC114EU-7-F	Commercial	N13	7	8	3,000
DDC114EUQ-7-F	Automotive	N13	7	8	3,000
DDC114EUQ-13-F	Automotive	N13	13	8	10,000
DDC113TU-7-F	Commercial	N01	7	8	3,000
DDC143TU-7-F	Commercial	N07	7	8	3,000
DDC114TU-7-F	Commercial	N12	7	8	3,000
DDC114TUQ-7-F	Automotive	N12	7	8	3,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>.
 3. For packaging details, go to our website at <http://www.diodes.com>.
 4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

Marking Information


NXX = Product Type Marking Code
 See Page 1 Diagrams
 YM = Date Code Marking
 Y = Year ex: T = 2006
 M = Month ex: 9 = September

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage		V _{CC}	50	V
Input Voltage	DDC124EU	V _{IN}	-10 to +40	V
	DDC144EU		-10 to +40	
	DDC114YU		-6 to +40	
	DDC123JU		-5 to +12	
	DDC114EU		-10 to +40	
	DDC113TU		-5V max	
	DDC143TU		-5V max	
DDC114TU	-5V max			
Output Current		I _{C(MAX)}	100	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. Mounted on FR4 PC Board with minimum recommended pad layout

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic (DDC113TU & DDC143TU & DDC114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	—	—	V	$I_C = 50\mu\text{A}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	50	—	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	5	—	—	V	$I_E = 50\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 50\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	0.5	μA	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_C/I_B = 2.5\text{mA} / 0.25\text{mA}$ DDC143TU $I_C/I_B = 1\text{mA} / 0.1\text{mA}$ DDC114TU $I_C/I_B = 10\text{mA} / 1\text{mA}$ DDC113TU
DC Current Transfer Ratio	h_{FE}	100	250	600	—	$I_C = 1\text{mA}, V_{CE} = 5\text{V}$
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product (Note 6)	f_T	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Input Voltage	$V_{I(off)}$	DDC124EU	0.5	1.1	—	V	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$
		DDC144EU	0.5	1.1	—		
DDC114YU		0.3	—	—			
DDC123JU		0.5	—	—			
DDC114EU		0.5	1.1	—			
	$V_{I(on)}$	DDC124EU	—	1.9	3.0	V	$V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 2\text{mA}$ $V_O = 0.3, I_O = 1\text{mA}$ $V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 10\text{mA}$
		DDC144EU	—	1.9	3.0		
		DDC114YU	—	—	1.4		
		DDC123JU	—	—	1.1		
		DDC114EU	—	1.9	3.0		
Output Voltage	$V_{O(on)}$	—	0.1	0.3	V	$I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$	
Input Current	I_I	—	—	0.36 0.18 0.88 3.6 0.88	mA	$V_I = 5\text{V}$	
Output Current	$I_{O(off)}$	—	—	0.5	μA	$V_{CC} = 50\text{V}, V_I = 0\text{V}$	
DC Current Gain	G_I	56 68 68 80 80 30	—	—	—	$V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$	
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—	
Resistance Ratio Tolerance	R_2/R_1	-20	—	+20	%	—	
Gain-Bandwidth Product (Note 6)	f_T	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$	

Notes: 6. Transistor - For Reference Only

Typical Curves – DDC123TK One Section

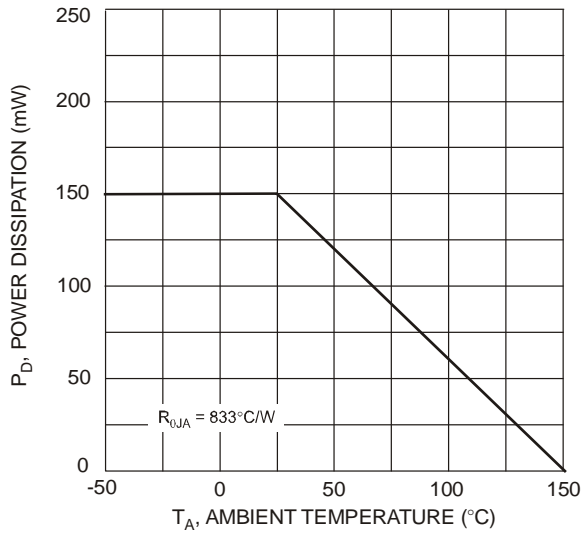


Fig. 1 Derating Curve

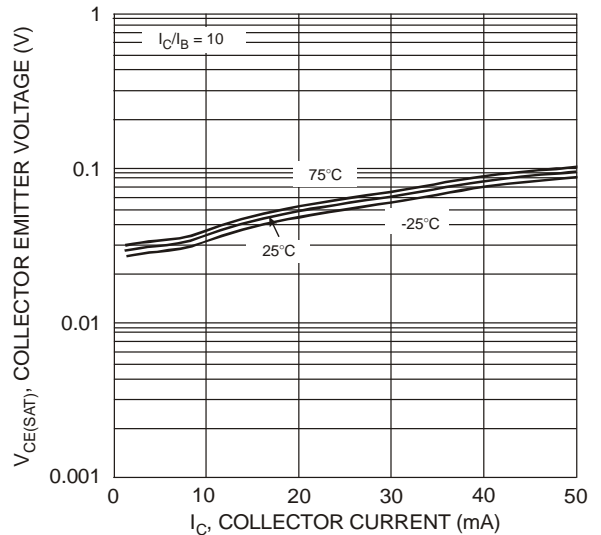


Fig. 2 $V_{CE(SAT)}$ vs. I_C

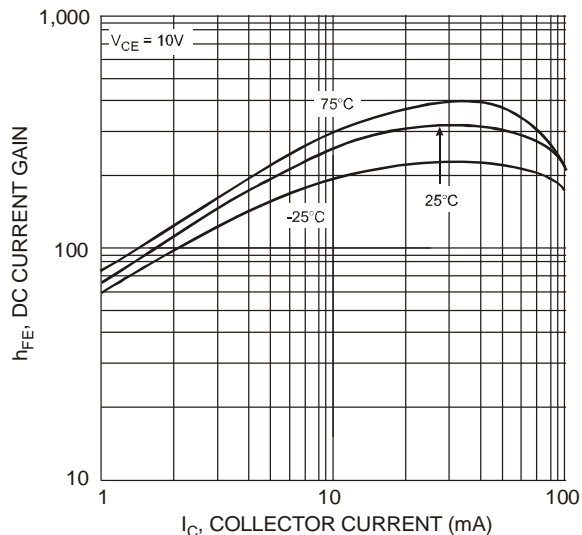


Fig. 3 DC Current Gain

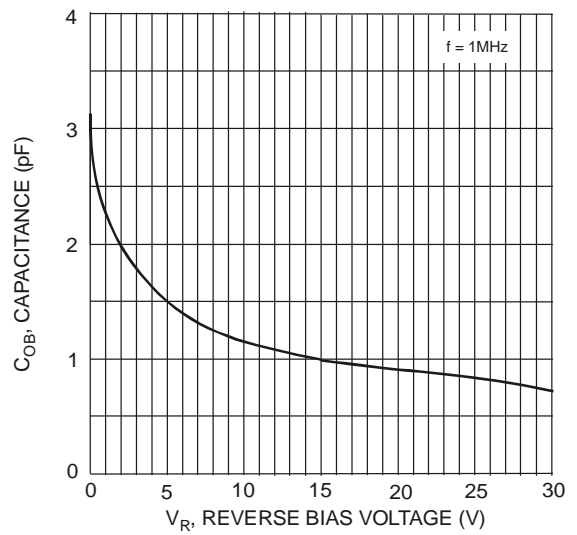


Fig. 4 Output Capacitance

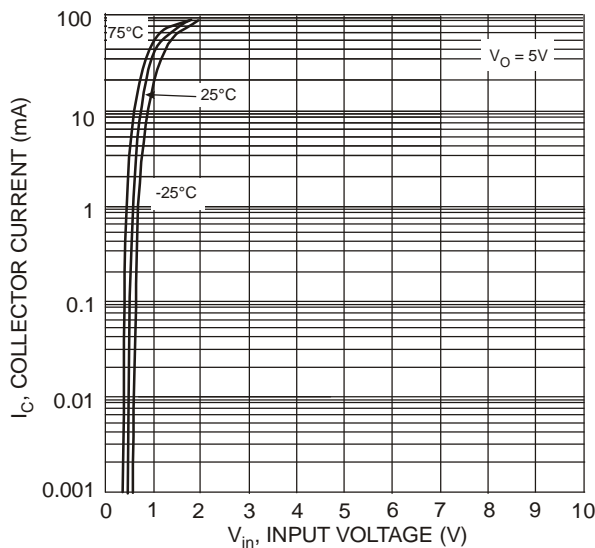


Fig. 5 Collector Current vs. Input Voltage

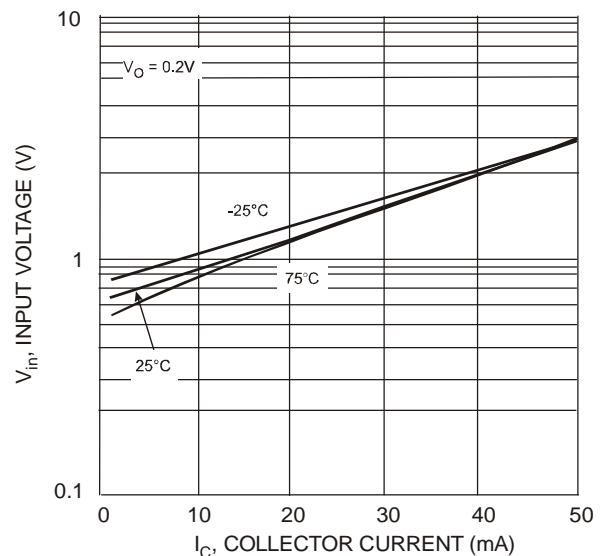


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDC114TK One Section

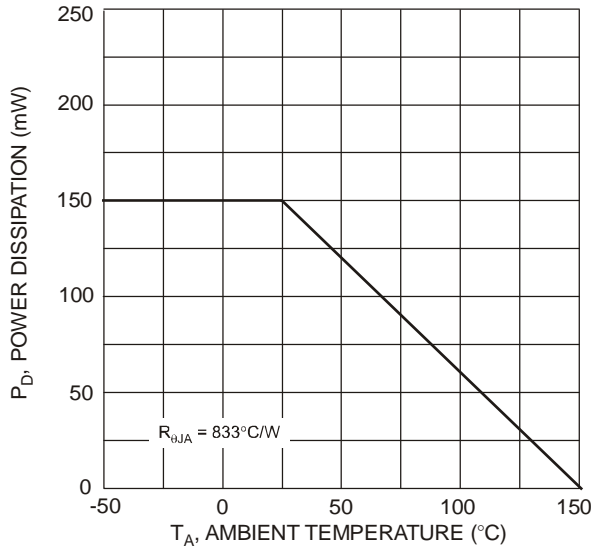


Fig. 1 Derating Curve

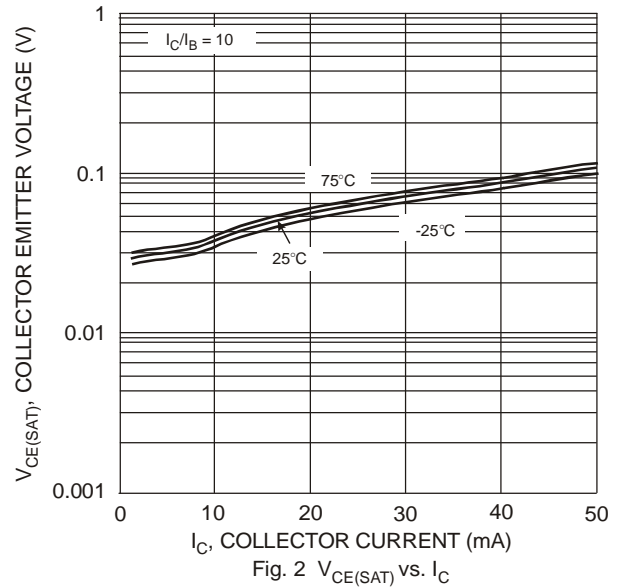


Fig. 2 $V_{CE(SAT)}$ vs. I_C

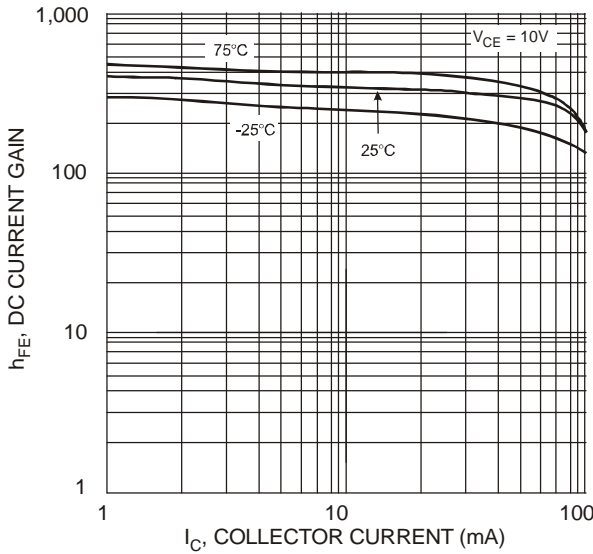


Fig. 3 DC Current Gain

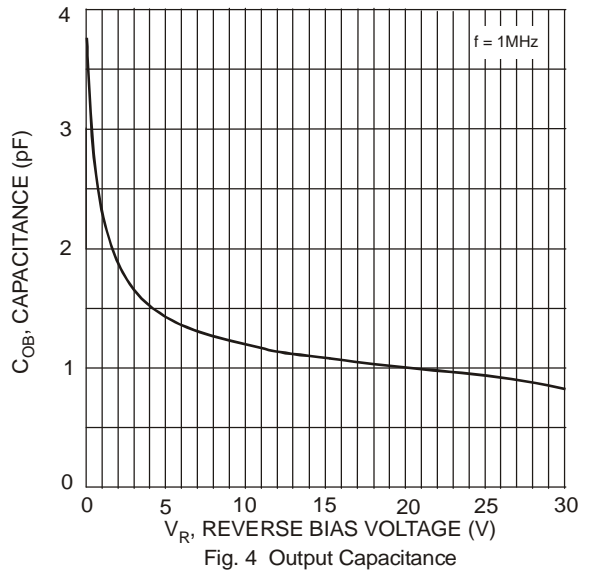


Fig. 4 Output Capacitance

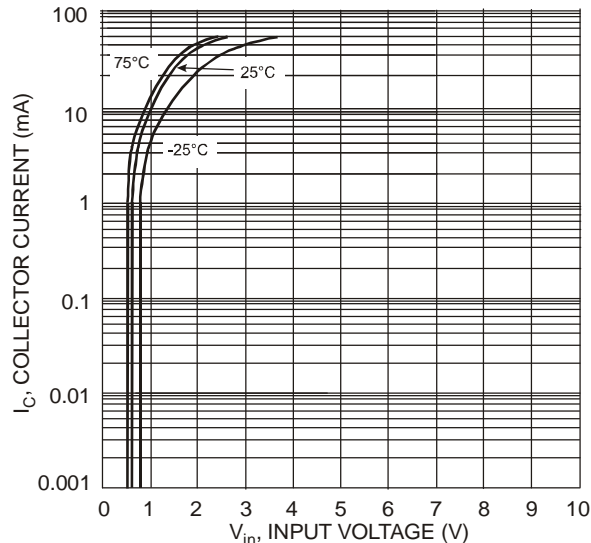


Fig. 5 Collector Current vs. Input Voltage

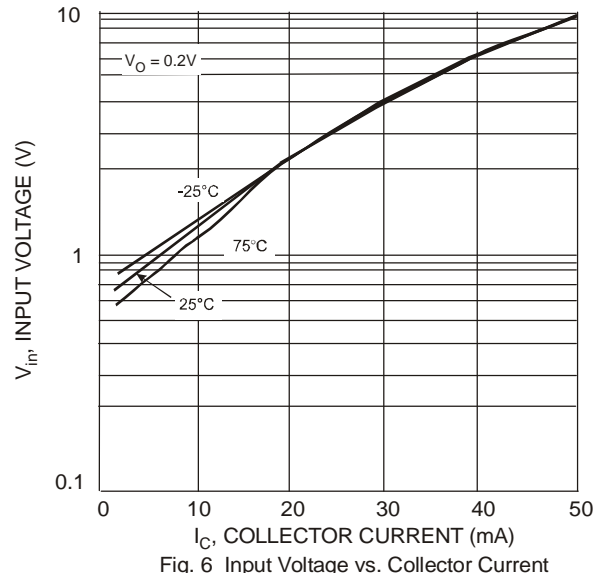
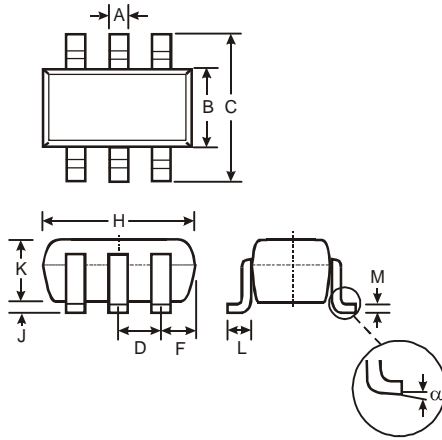


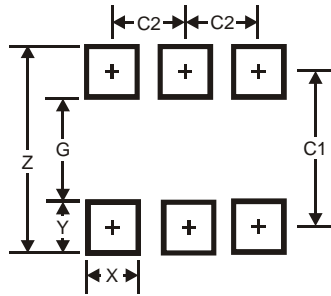
Fig. 6 Input Voltage vs. Collector Current

Package Outline Dimensions



SOT363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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